

Study on Electrochromic Execution of Nickel Oxide Thin Films Prepared by Sol-Gel Route

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Abstract – Nanostructure metal oxide films has produced enthusiasm throughout the years because of their wide application (Ahuja D, Tatsutani M. 2009). They are utilized in radiation detectors, sun oriented cells, semiconducting gadgets, laser materials, thermoelectric device, and optoelectronic devices. Nanostructured metal oxide is a promising alternative for thin film sun oriented cells. NiO is one such metal oxide with numerous reasonable properties. The NiO thin films were portrayed for their auxiliary, compositional, morphological, electro chromic, optical and colorimetric properties utilizing X-beam diffraction, X-Ray photoelectron spectroscopy (XPS), Scanning electron microscopy (SEM), FT-IR spectroscopy, cyclic voltammetry (CV), and optical transmittance and CIE arrangement of colorimetric estimations separately. The present study manages the readiness of NiO thin films by utilizing basic and minimal effort sol-gel plunge covering and its electro chromic execution.

Keywords: Electro Chromic, Nickel Oxide, Thin Films, Sol-Gel Route.

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INTRODUCTION

The nickel oxide (NiO) thin films have been set up from nickel acetic acid derivation forerunner by sol-gel plunge covering procedure. As stored films were toughened at 400 oC to get NiO thin films. The NiO thin films were portrayed for their auxiliary, morphological, compositional, electro chromic, colorimetric and optical properties utilizing X-beam diffraction, Scanning electron microscopy (SEM), X-Ray photoelectron spectroscopy (XPS), cyclic voltammetry (CV), FT-IR spectroscopy, CIE arrangement and optical transmittance of colorimetric estimations separately.

A savvy window (gadget) with the design: glass/ITO/NiO/KOH/ITO/glass was created utilizing the thin film and EC parameters were assessed. Nickel oxide (NiO) is an anodically shading material. In any case, in spite of promising highlights, for example, high electrochromic proficiency, great cycling reversibility, cost viability (Ebhotu WS, et.al., 2014) and dim tinge valuable for brilliant window innovation, NiO is the minimum comprehended of the electro chromic materials. The electrochromism in NiO thin films is fairly confounded, despite the fact that it is for the most part acknowledged that the reversible change among hued and faded states is identified with redox process between the (Ni²⁺) and (Ni⁴⁺) states (Islam AS, Islam M 2005).

NiO films are normally arranged by warm dissipation (Eslamian M 2014), sputtering (Vasu V, Subrahmanyam A 1990) and electrochemical testimony (Sakhare YS, et.al., 2016). These lively strategies are not constantly appropriate for substantial scale generation. Likewise manufacture cost is one of the best obstructions to advancement of the extensive territory brilliant windows (Manificier J, 1981, Joshi S, et.al., 2014).

An elective strategy is the ease sol-gel joined with plunge covering system (Czapla A, 1989, Drevet R, 2015]. The sol-gel strategy offers a low-temperature (room temperature) technique for blending materials on extensive zone that are either absolutely inorganic in nature or both inorganic and natural. The procedure, which depends on the hydrolysis and buildup response of organometallic mixes in alcoholic arrangements, offers numerous points of interest for the manufacture of coatings, including phenomenal control of the stoichiometry, simplicity of compositional adjustments, adaptable microstructure, simplicity of presenting different utilitarian gatherings or exemplifying detecting components, generally low toughening temperatures, the likelihood of covering testimony on vast zone substrates with a straightforward and modest hardware. In the ongoing years, various advancements in covering procedures and gear mechanization have made the sol-gel method significantly more far reaching.

Writing overview demonstrates that sol-gel NiO films have been stored from arrangements of nickel sulfate in liquor (Jlassi M, et.al., 2014) or nickel chloride ($\text{NiCl}_2 \cdot 6\text{H}_2\text{O}$) in liquor and ethylene glycol (Rahal A, et.al., 2015). There are concerns, be that as it may, about the nearness of chlorine in the films weakening the reversibility of the cycling. Films have been kept from nickel nitrate $\text{Ni}(\text{NO}_3)_2 \cdot 6\text{H}_2\text{O}$ in ethylene glycol or liquor (Sharon M, Prasad B 1983). The warm dependability of metal nitrates are probably going to limit its utilization to little scale applications. As of late, NiO films kept from nickel diacetate forerunner in methanol have been accounted for (Czapla A, Kusior E, Bucko M 1989). Sol-gel statement of NiO has been limited by an absence of appropriate forerunners, which have adequate dissolvability and steadiness in liquor solvents. Most basic nickel alkoxides are polymeric and insoluble in liquor at room temperature (Zhang W, et.al., 2006).

METHODOLOGY

Preparation of Nickel Oxide Thin Films

Nickel hydroxide thin films were saved on Indium doped Tin Oxide (ITO) (Kintec corp. Ltd, Hong Kong) covered straightforward leading glass having sheet opposition of 25-40 Ω/cm^2 , by means of sol-gel course utilizing 0.5 M nickel diacetatetetrahydrate ($\text{Ni}(\text{CH}_3\text{COO})_2 \cdot 4\text{H}_2\text{O}$), in 50 ml ethanol and 0-5 ml of HCl. The subsequent arrangement was refluxed for 1 h at 60 °C and permitted to cool at room temperature. The arrangement was greenish straightforward in nature. Before testimony, ITO's were cleaned with ultrasonic treatment in CH_3COOH and de-ionized water individually. Thin films were saved by plunge covering with ten affidavit cycles and tempered at 400 °C at 90 min to get NiO.

Fabrication of Sol-gel Deposited NiO Electrochromic Device

The EC gadget arrangement for sol-gel saved NiO thin film was Glass/ITO/NiO/KOH/ITO/Glass. The schematic chart of the sandwich-type EC gadget is appeared in Fig.4.1.

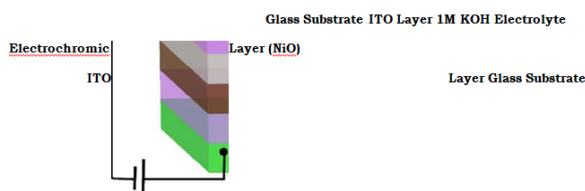


Figure.3.1. The schematic diagram of the NiO thin film based electrochromic device.

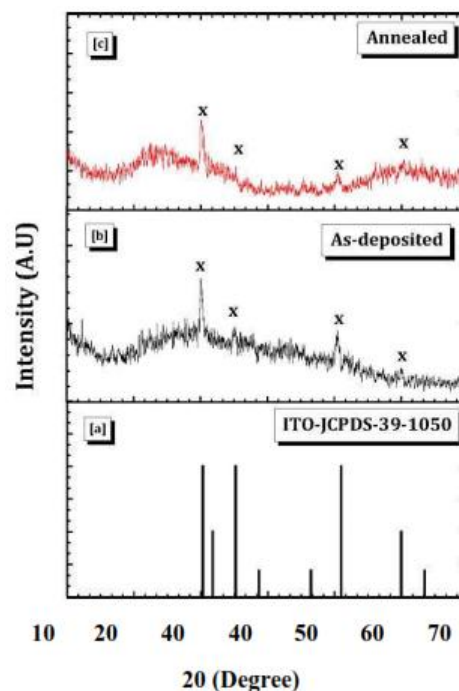


Figure.4.2: XRD patterns of (a) The peaks characteristic of ITO, NiO thin film in (b) As deposited and (c) annealed at 400 °C for 90 min

NiO thin films stored on ITO covered directing glass substrate goes about as a working anode and ITO covered leading glass substrate goes about as counter terminal were amassed together with twofold sided tesco tape of 1.5 mm thickness to deliver a sandwich-type electrochromic gadget. The fluid electrolyte (1M KOH) was filled into the gadget through a little gap and fixed it with resibond epoxy stick. The EC gadget was dried in air for 1 day before contemplating EC execution.

Characterization

The auxiliary properties of the NiO thin films were examined with X-beam diffractometer (Philips, PW 4710, Almelo, Holland) worked at 25 kV, 20 mA with Cu ka radiation ($\lambda = 1.54 \text{ \AA}$). The infrared (IR) range was recorded utilizing Perkin-Elmer IR spectrophotometer (display 100) in the unearthly range 400-4000 cm^{-1} . The pellets were set up by blending KBr with NiO powder gathered by scratching film from glass substrate in the proportion 400:1 and after that squeezing the powder between two bits of cleaned steel. The surface morphology of the films was analyzed by examining electron microscopy (SEM) (Model JEOL-JSM-6460, Japan) and a field emanation filtering electron magnifying lens (FESEM, JEOL JSM-6500F). The natural and basic data of the NiO thin films were investigated utilizing X-beam photoelectron spectrometer (XPS, VG Multilab 2000-Thermo Scientific Inc. UK, K-alpha) with a micro focus monochromated Al Ka X-beam working with high photonic energies from 0. 1 to 4 KeV. Amid the information preparing of the XPS spectra,

restricting vitality esteems were aligned by the C-1s top (284.6 eV) from the unusual tainting layer. A Shirley-type foundation was subtracted from the signs and the pinnacles were deconvoluted by Gaussian-Lorentz fitting utilizing XPSPEAK programming. The electrochromic estimations were performed in an electrolyte of 1 M KOH in an ordinary three-cathode plan including NiO thin film as a working anode, platinum wire as the counter terminal and immersed calomel anode (SCE) as the reference anode utilizing an electrochemical quartz gem (EQCM) (show CHI-400A) by CH Instrument, USA. In-situ transmittance was recorded utilizing a He-Ne Laser ($\lambda=642.8$ nm), a Si photodiode and a capacity oscilloscope. To get the $L^*a^*b^*$ and Yxy organize values, colorimetric judgments were recorded by investigating the transmittance spectra of shading/dye state utilizing Shimadzu shading examination programming. Using the assessed CIE $L^*a^*b^*$ and Yxy arrange values, the shading in lessened and oxidized state was gotten by 1941 2o spectator and D-65 illuminant.

RESULTS AND DISCUSSION

X-Ray Diffraction (XRD) Studies

Fig.4.2 demonstrates the XRD examples of the films stored on ITO covered glass substrate in as saved and tempered at 400 oC. No trademark diffraction pinnacles of NiO were identified even in the wake of strengthening suggesting that NiO film was dominantly shapeless.

Fourier Transform Infrared (FT-IR) Spectroscopic Studies

The IR spectroscopy is a unique finger impression of concoction structure of the material. It gives clear proof of the holding framework in the material. The infrared retention modes are identified with dipole snapshots of the useful gatherings in the material. An examination between IR spectra of crystalline mass and that of thin film uncovers the level of hydroxylation and hydration in the saved example. The utilitarian gatherings in the material demonstrate their trademark retention crests when recurrence of IR radiation is equivalent to the normal recurrence of sub-atomic vibration. Accordingly a retention top in IR range demonstrates the nearness of practical gathering in the example. Correlation between IR spectra of thin film and crystalline mass is generally perfect.

Fig.4.4 (a, b) demonstrates the IR transmission spectra of the as kept and toughened NiO tests recorded more than 400-4000 cm^{-1} territory. The expansive and extreme band focused at 4421 cm^{-1} is doled out to the O-H extending vibration of the interlayer water atoms and of the H-bound OH aggregate in the as saved example. The pinnacle saw at 1640 cm^{-1} is doled out to the bowing vibration

of water atoms (Farhadi S, et.al., 2011). The pinnacles comparing to vibrations of scaffold fortified acetic acid derivation bunches are seen at 1028 cm^{-1} and 1415 cm^{-1} (Salavati-Niasari M, Mir N, Davar F 2010). The band situated at 674 cm^{-1} comparing to in-plane $\delta(\text{Ni-OH})$ misshapening and the 466 cm^{-1} band because of Ni-O extending vibration $\nu(\text{Ni-O})$ (Wang L, Hao Y, Zhao Y, Lai Q, Xu X 2010). The lessening in force of the band focused at 4421 cm^{-1} demonstrates that tempering expels some measure of hydration, prompting the NiO development

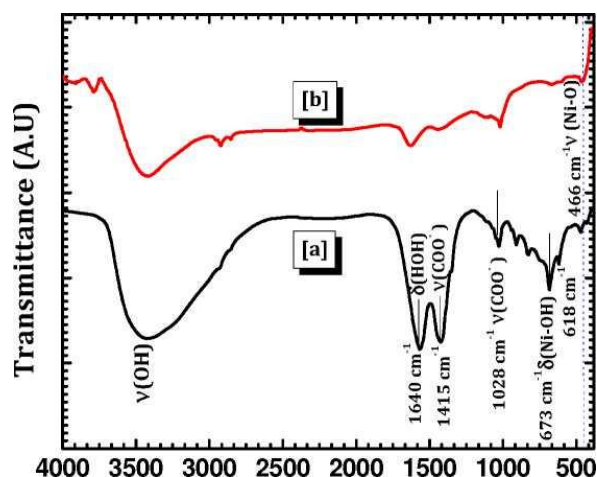


Figure.4.4: FT-IR spectra of (a) As deposited and (b) annealed NiO samples scratched from thin films

X-Ray Photoelectron Spectroscopic (XPS) Studies

Restricting vitality (eV)

Figure 4.4 (a) demonstrates the overview range of the nickel oxide kept by sol-gel course and strengthened at 400 oC. The main components distinguished on the surface of toughened film are nickel, oxygen and furthermore some carbon demonstrating photoelectron crests, Ni2p for nickel, O-1s for oxygen and C-1s for carbon. Nearness of environmental carbon is likely and, truth be told, usually used to align crest positions. The high goals XPS range of Ni (2p) and O (1s) center dimensions is appeared in Fig.4.4 (b, c).

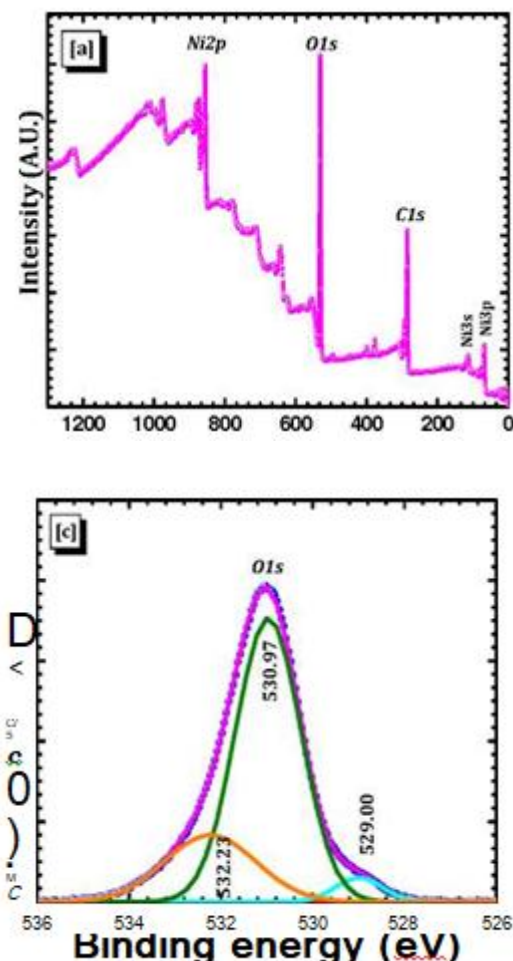


Figure.4.4: The high resolution XPS spectrum (a) Wide scanning XPS spectrum of NiO, (b) core level spectra of Ni (2p) (c) core level spectra of O (1s) and (d) C (1s).

The trial spectra of Ni 2p were deconvoluted by Gaussian bends into five distinct pinnacles. The Ni 2p spectra involve two locales speaking to the Ni 2p_{4/2} (850-865 eV) and Ni 2p_{1/2} (870-885 eV) turn circle levels. This twofold pinnacle highlight of Ni (2p), relates to the Ni (2p_{4/2}) and Ni (2p_{1/2}) situated at a coupling vitality of 855.45 and 872.41 eV individually as found in Fig. 4.4 (b) is obviously uncovered. The shake-up satellite pinnacles were seen at ~5.51 eV and ~6.01 eV higher restricting vitality than that of Ni (2p_{4/2}) and Ni (2p_{1/2}) crests, separately. The pinnacle of Ni (2p_{4/2}) at a coupling vitality of 855.45 with their attendant shake-up satellite tops at 860.96 showed the nearness of Ni²⁺ cations and not of Ni⁴⁺ cations. The equivalent is watched for Ni (2p_{1/2}) top. This perception affirmed the sol-gel kept NiO was made out of unadulterated NiO stage (Wu J, Xue D 2011, Pavan M, et.al., 2015). The vitality partition of 17.58 eV saw between Ni (2p_{4/2}) and Ni (2p_{1/2}) tops relegated to NiO, which is in well concurrence with the prior reports.

The O-1s XPS range of NiO film is appeared in Fig. 4.4 (c) after deconvolution into three pinnacles. The

outcomes demonstrated a fit to three pinnacles situated at 529, 540.97 and 542.24 eV. The high extreme pinnacle situated at B.E. of 540.97 eV with shoulder crest at 529 eV relates to the O-1s center dimension of the O²⁻ anions in the NiO. The shoulder top has been proposed for the imperfection destinations inside the oxide precious stone adsorbed oxygen or hydroxide species. The coupling energies of the primary and satellite tops in the O-1s and Ni-2p center dimensions are predictable with NiO. The lower restricting vitality top relates to the O-1s center dimension of the O²⁻ anions in the NiO. The O-1s crest was identified with the Ni-O synthetic holding. The higher restricting vitality crest at 542.24 eV was ascribed the H-O-H bond for the remaining water. This again affirms the NiO thin film is made out of unadulterated stoichiometric NiO stage.

Surface Morphological Studies

The Scanning electron micrograph pictures of NiO thin film arranged by a sol-gel strategy are appeared in Fig.4.5 at changed amplifications. In spite of the fact that the surface is by all accounts conservative and smooth at lower amplification (5000X), it is a permeable system of smaller scale granules.

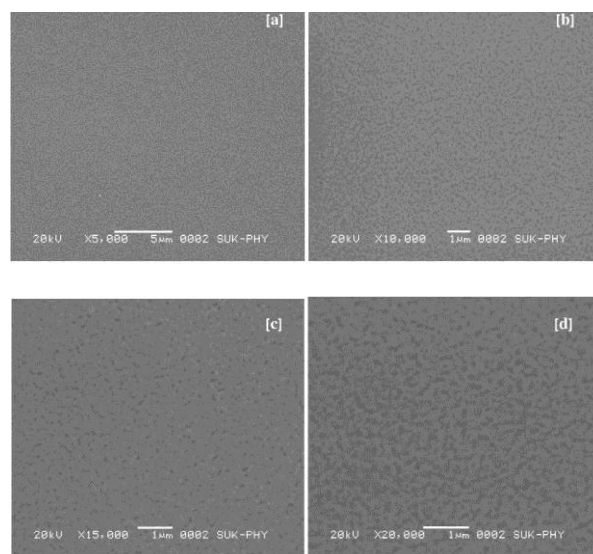
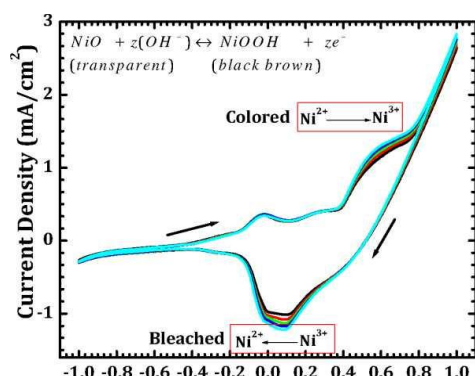


Figure.4.5: SEM images of NiO thin film at (a) 5,000 X (b) 10,000 X (c) 15,000 X and (d) 20,000 X magnification. 4.4.5: Electrochromic Properties

Cyclic Voltammetry (CV) was utilized to research the electrochromic (cathodic/anodic) conduct of NiO. Fig.4.6 presents the CV of the sol gel stored NiO, which was recorded for initial five cycles at an output rate of 50 mV/sec in 1 M KOH electrolyte with straight potential range between ± 1 V versus SCE. The bolts speak to the forward and switch examine headings. Amid the anodic (positive potential) examine, OH-particles are intercalated into the NiO film, the Ni²⁺ particles get oxidized to Ni⁴⁺ and the straightforward NiO film swings to dull

darker (anodically shading material). Amid the cathodic (negative potential) filter, deintercalation of OH-particles from the film happens Ni⁴⁺ particles are decreased to Ni²⁺ and the NiO film ended up straightforward once more (blanching).

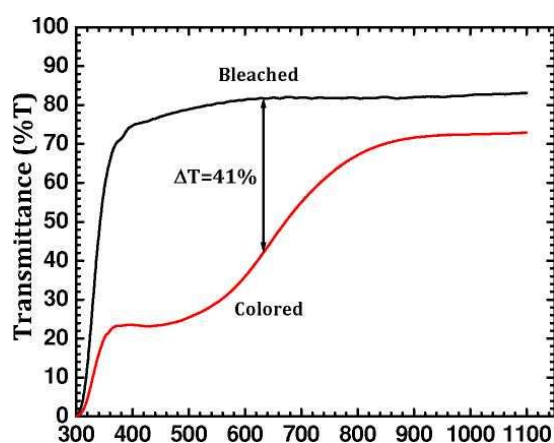


Applied Voltage (V) vs SCE

Figure.4.6: Cyclic voltammogram for sol gel deposited NiO thin film.

Table.4.1: Electrochromic parameters for sol gel deposited NiO thin films

| | |
|--|---------------------------|
| Anodic potential (mV/s) | 600 mV |
| Cathodic potential (mV/s) | 100 mV |
| Anodic peak current (mA/cm ²) | 1.41 |
| Cathodic Peak current (mA/cm ²) | 1.20 |
| Transmittance (%T) | Tc 82 |
| | Tb 41 |
| Transmittance difference (AT %) | 41 |
| Optical Density change (AOD) | 0.68 |
| Response Time (sec) | tc 5.95 |
| | tb 4.50 |
| Diffusion coefficient (cm ² /S) | Di 7.48x10 ⁻¹¹ |
| | Dd 6.27x10 ⁻¹¹ |
| Coloration efficiency - n (cm ² /C) | 42 |



Wavelength (nm)

Cyclic Voltammetry (CV) was utilized to research the electrochromic (cathodic/anodic) conduct of NiO.

Fig.4.6 presents the CV of the sol gel kept NiO, which was recorded for initial five cycles at an output rate of 50 mV/sec in 1 M KOH electrolyte with direct potential breadth between ± 1 V versus SCE. The bolts speak to the forward and turn around sweep bearings. Amid the anodic (positive potential) examine, OH-particles are intercalated into the NiO film, the Ni²⁺ particles get oxidized to Ni⁴⁺ and the straightforward NiO film swings to dim darker (anodically shading material). Amid the cathodic (negative potential) filter, deintercalation of OH-particles from the film happens Ni⁴⁺ particles are lessened to Ni²⁺ and the NiO film ended up straightforward once more (dying).

A disentangled redox conspire demonstrating the optical changing because of intercalation/deintercalation of OH-particles and electrons in electrochromicNiO film spoken to by following conditions;

NiO (straightforward) + z(OH⁻) \wedge NiOOH (dull darker) + ze⁻ or

Ni(OH)₂ + zOH⁻ \wedge NiOOH + H₂O + ze⁻ (4.1)

The Diffusion coefficient (D) for the OH-particles for intercalation (Di) and deintercalation (Dd) was assessed from the Randles-Sevcik condition.

Where n is the quantity of electrons thought to be 1, Co is the centralization of dynamic particles in the electrolyte, v the output rate, jp is the anodic or cathodic pinnacle current thickness and An is surface territory of the film. The qualities are demonstrated in Table.4.1.

Optical Transmittance Studies

Fig.4.8 demonstrates the optical transmission spectra of shaded and blanched conditions of sol gel saved NiO thin film, in the wavelength run 400 to 1100 nm. The optical transmittance in hues (Tc) and faded (Tb) states at 640 nm were 42 % and 82 % showing an optical transmittance adjustment (AT) of 41 %. Hence the film morphology gives the appropriate conductors to intercalation/deintercalation of OH-particles.

In-situ transmittance estimation was utilized to ponder the exchanging attributes of the sol-gel kept NiO thin films. The single hue and fading cycle appeared in Fig.4.9 delineates the exchanging time reaction attributes. The exchanging reaction times were computed on the dimension of a 80 % transmittance change. For shading it is indicated by tc and for dying by tb. The exchanging times for these NiO thin films were observed to be 5.95/4.50 s for tinge and fading which is much lower than those for NiO nanowalls.

The hue proficiency (CE) decides the measure of optical thickness change (AOD) as an element of the infused/launched out electronic charge (Q_i) at a particular wavelength, i.e., the measure of charge required for changing the optical thickness. It is given by,

The tinge productivity of the sol gel stored NiO thin films was observed to be 42 cm²/C, which is bigger than that detailed for NiO thick and thin films (28.8 cm²/C), separately. The enhanced CE might be credited to the bigger textural limits and bigger dynamic surface region, where real shading/blanching forms happen.

Colorimetric Analysis

The calorimetric estimations were utilized as a quantitative scale to decide the shades of sol gel saved NiO thin film. The properties of shading, tint - an (its situation among red and green, where negative qualities tends towards green and positive qualities inclines toward red), immersion b (its situation in the middle of blue and yellow, where negative esteem inclines toward blue and positive esteem inclines toward yellow) and gentility L (where 0 is dark and 100 is white shading), A two-dimensional x-y portrayal known as the chromaticity graph used to decide the shades of NiO thin film are appeared in Fig.4.10 (a, b) individually. The x and y were ascertained from the tristimulus esteems. The move in x-y co-ordinates happens once the potential was changed from decrease (dying) to oxidation (tinge) states. The move in x-y co-ordinates shows that, the shade of the NiO tremendously changes from exceedingly transmittive (blanched shown by white guide) state toward profound dark colored absorptive state. To distinguish the murkiness/brilliance as for connected potential, the softness was ascertained from $L^*a^*b^*$ organizes. The delicacy contrast (AL) of 29.41% was watched. These chromaticity parameters were broke down from transmittance spectra in the range 480-780 nm of shaded and dyed conditions of NiO thin film. These parameters are recorded in Table.4.2.

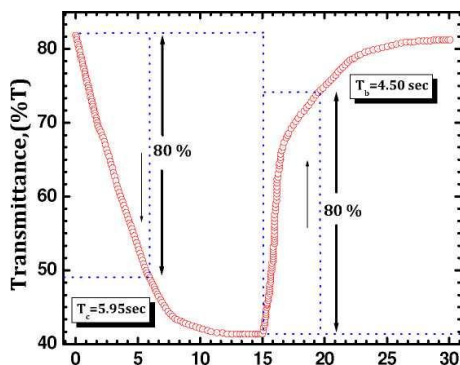


Figure.4.9: In-situ transmittance response of the NiO thin film for 15 sec

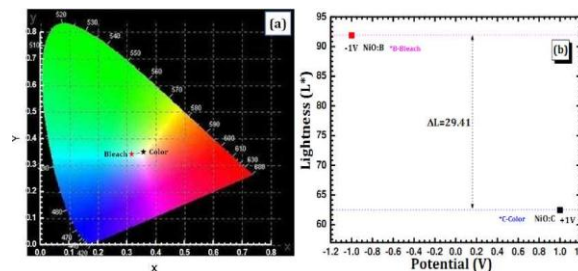


Figure.4.10: (a) CIE 1931 Yxy chromaticity diagram for 2° observer and D-65 illuminant. The straight line shows variations in x-y values and Lightness vs applied potential for sol gel deposited NiO thin-film in its colored and bleached states. Dashed vertical lines indicate difference of lightness in its colored and bleached state. Table.4.2: Chromaticity parameters for sol gel deposited NiO thin films

| Device | Y | x | y | L* | a* | b* | AL* |
|--------------------|-------|--------|--------|-------|-------|-------|-------|
| NiO-Bleached State | 80.48 | 0.4172 | 0.4448 | 91.86 | -0.01 | 2.48 | 29.41 |
| NiO-Colored State | 40.94 | 0.458 | 0.4494 | 62.45 | 8.58 | 11.44 | |

CONCLUSIONS

Sol-gel kept NiO films were effectively developed from sols of nickel acetic acid derivation. The NiO stage development is affirmed by XRD and XPS contemplates. The morphological investigations uncovered that the film made out of permeable small scale granule structure. The optical transmittance and in-situ transmittance estimation demonstrated that the film displayed transmittance distinction (AT) of 41 % and reaction time of 5.95/4.44 s for tinge and dying individually. The chromaticity estimations demonstrated a daintiness distinction of about 29.41 %. The tinge proficiency was observed to be 42 cm²/C at 640 nm.

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